



Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 40 and 60 V

Forward Current - 2.0A

Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg / 0.00095oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View

Marking Code: SSL24 /SSL26

Simplified outline SMAF and symbol

Maximum Ratings and Electrical characteristics

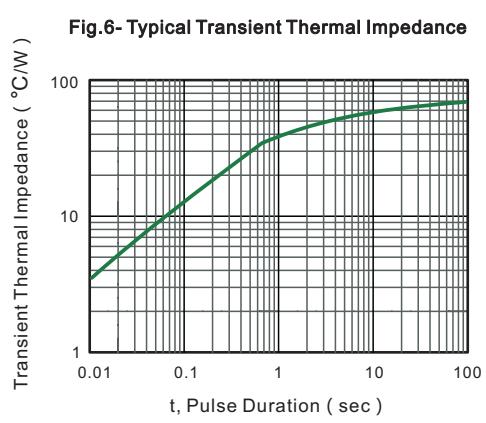
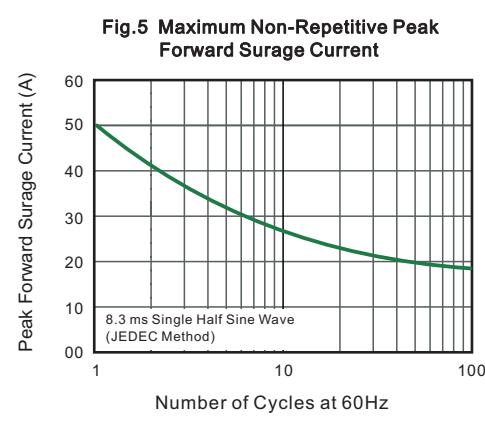
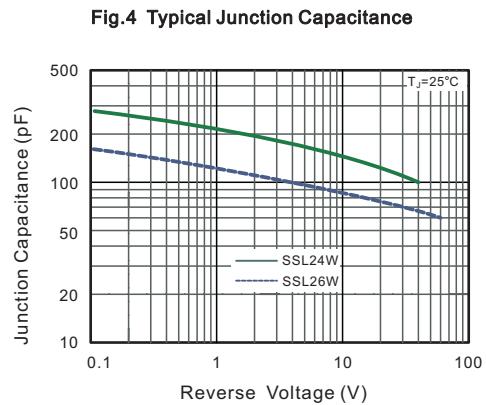
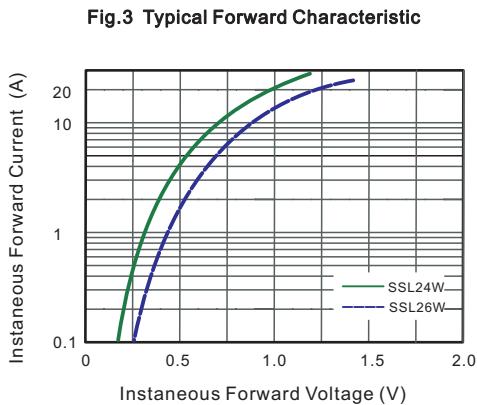
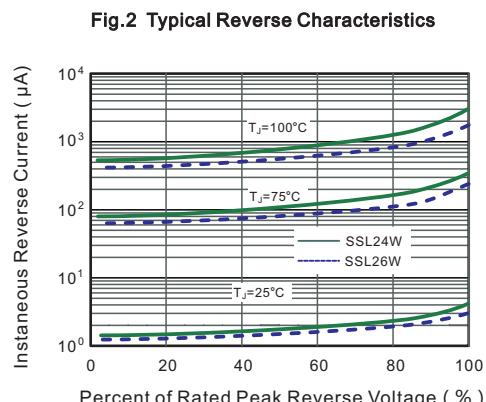
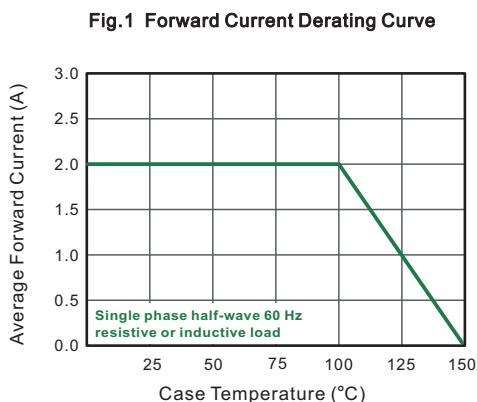
Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	SSL24F	SSL26F	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	40	60	V
Maximum RMS voltage	V_{RMS}	28	42	V
Maximum DC Blocking Voltage	V_{DC}	40	60	V
Maximum Average Forward Rectified Current at $T_c = 100^\circ C$	$I_{F(AV)}$	2		A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	50		A
Maximum Instantaneous Forward Voltage at 2 A	V_F	0.45	0.52	V
Maximum DC Reverse Current $T_a = 25^\circ C$ at Rated DC Blocking Voltage $T_a = 100^\circ C$	I_R	0.5 10	0.3 5	mA
Typical Junction Capacitance ⁽¹⁾	C_j	290	130	pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	70		°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150		°C
Storage Temperature Range	T_{stg}	-55 ~ +150		°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

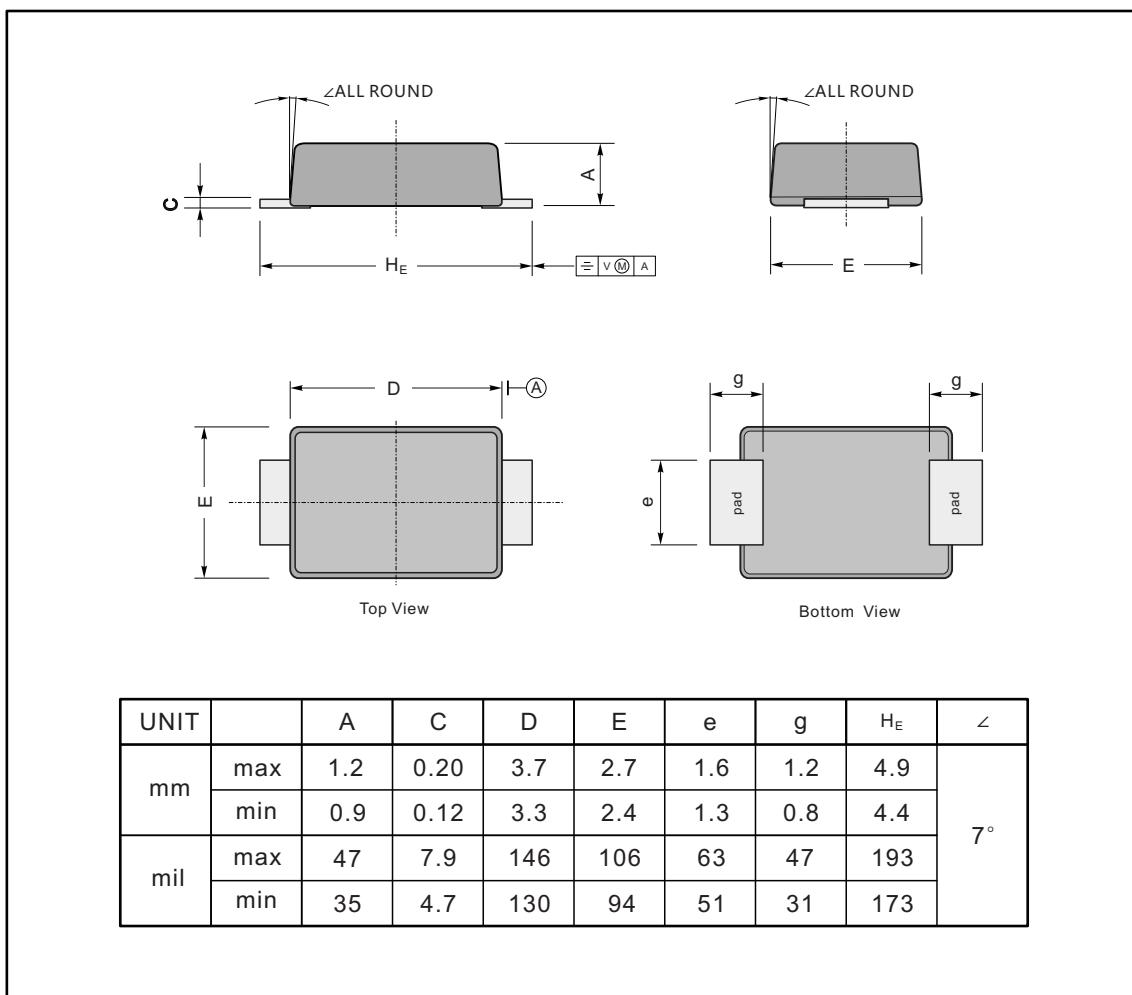




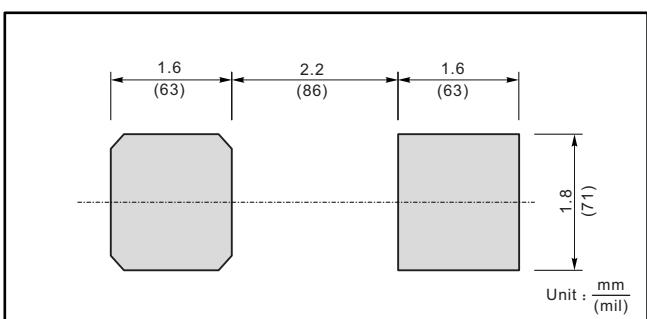
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMAF



The recommended mounting pad size



Marking

Type number	Marking code
SSL24F	SSL24
SSL26F	SSL26